

Features

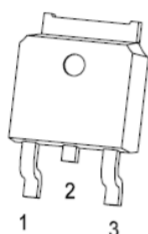
- $V_{DS} = -60V, I_D = -16A$
 $R_{DS(ON)} = 52m\Omega @ V_{GS} = -10V (Typ)$

Application

- Load/Power Switching
- Interfacing Switching
- Battery Management for Ultra Small Portable Electronics
- Logic Level Shift

Package and Pin Configuration

TO-252



1. GATE
2. DRAIN
3. SOURCE

Marking:



Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	± 20	V
Drain Current-Continuous	I_D	-16	A
Drain Current-Continuous ($T_C = 100^\circ C$)	$I_D (70^\circ C)$	-10.5	A
Pulsed Drain Current	I_{DM}	-53	A
Maximum Power Dissipation	P_D	20	W
Derating factor		0.4	W/ $^\circ C$
Single pulse avalanche energy ^(Note 5)	E_{AS}	35	mJ
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55 To 175	$^\circ C$

Thermal Characteristic

Thermal Resistance, Junction-to-Case ^(Note 2)	$R_{\theta JC}$	6.0	$^\circ C/W$
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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-60V, V _{GS} =0V	-	-	-1	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.8	-2.5	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =-10V, I _D =-6A	-	52	60	mΩ
		V _{GS} =-4.5V, I _D =-4A	-	65	80	mΩ
Forward Transconductance	g _{FS}	V _{DS} =-5V, I _D =-16A	-	10	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C _{iss}	V _{DS} =-30V, V _{GS} =0V, F=1.0MHz	-	1100	-	PF
Output Capacitance	C _{oss}		-	90.6	-	PF
Reverse Transfer Capacitance	C _{rss}		-	77.3	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t _{d(on)}	V _{DD} =-30V, R _L =1.5Ω, V _{GS} =-10V, R _G =3Ω	-	11	-	nS
Turn-on Rise Time	t _r		-	14	-	nS
Turn-Off Delay Time	t _{d(off)}		-	33	-	nS
Turn-Off Fall Time	t _f		-	13	-	nS
Total Gate Charge	Q _g	V _{DS} =-30, I _D =- 6A, V _{GS} =-10V	-	37.6		nC
Gate-Source Charge	Q _{gs}		-	4.3		nC
Gate-Drain Charge	Q _{gd}		-	7.2		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V, I _S =-16A	-		-1.2	V
Diode Forward Current (Note 2)	I _S			13		A
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F =- 13A di/dt = -100A/μs (Note3)	-	35		nS
Reverse Recovery Charge	Q _{rr}		-	38		nC
Forward Turn-On Time	t _{on}	Intrinsic turn-on time is negligible (turn-on is dominated by LS+LD)				

Typical Characteristics

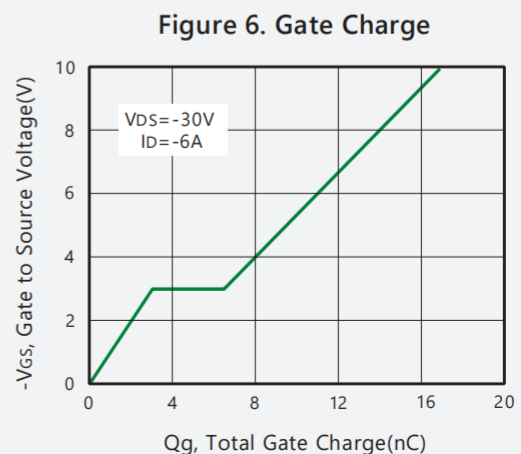
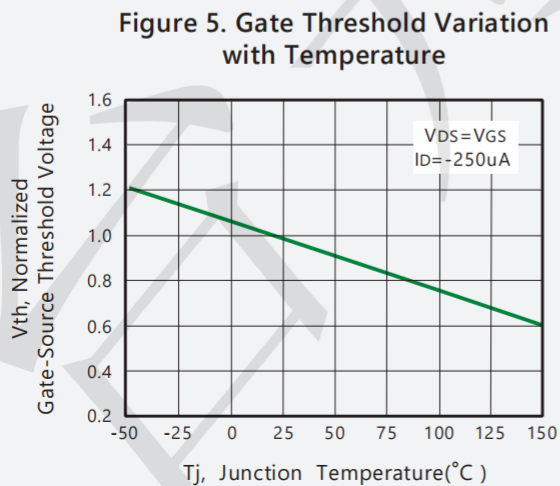
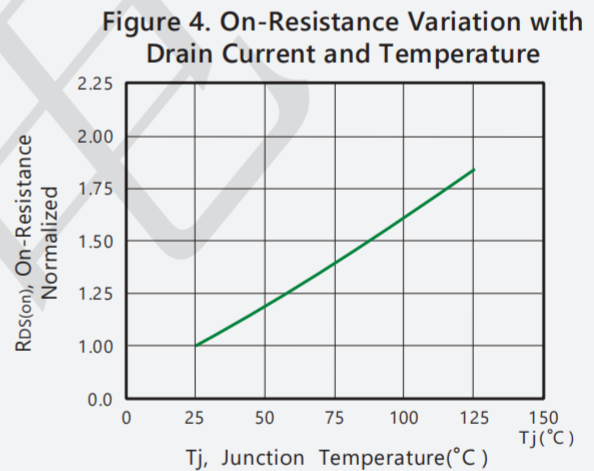
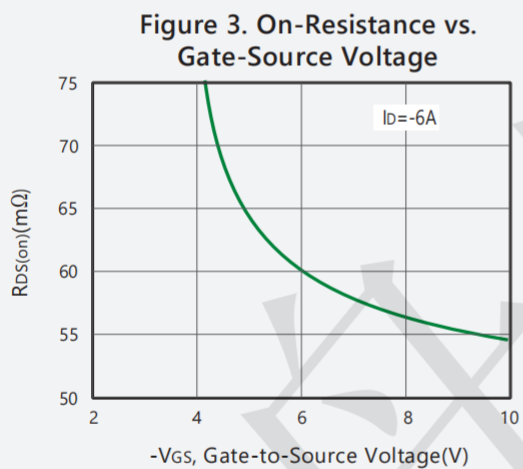
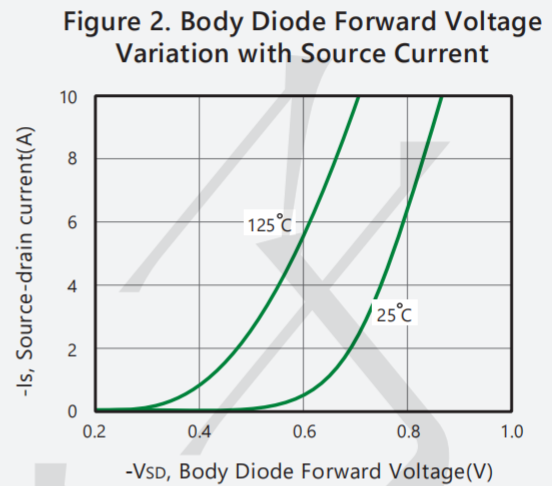
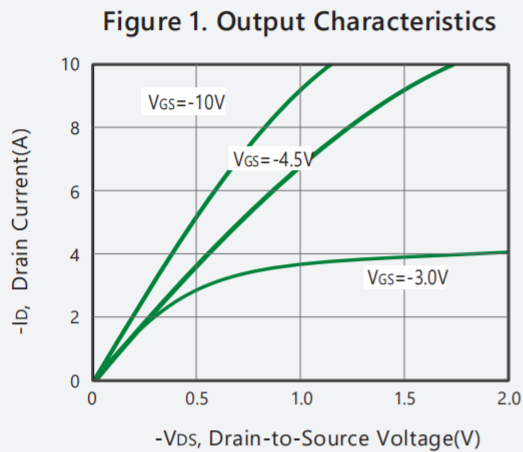


Figure 7. Capacitance

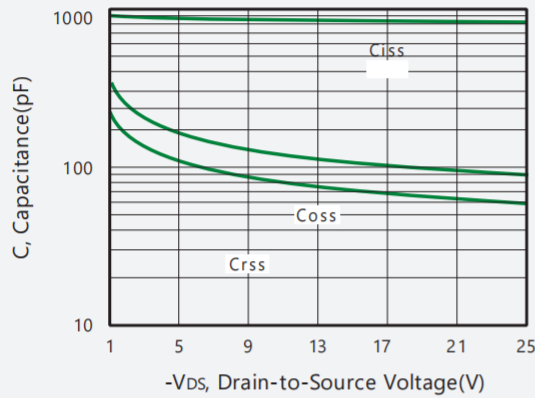


Figure 8. Maximum Safe Operating Area

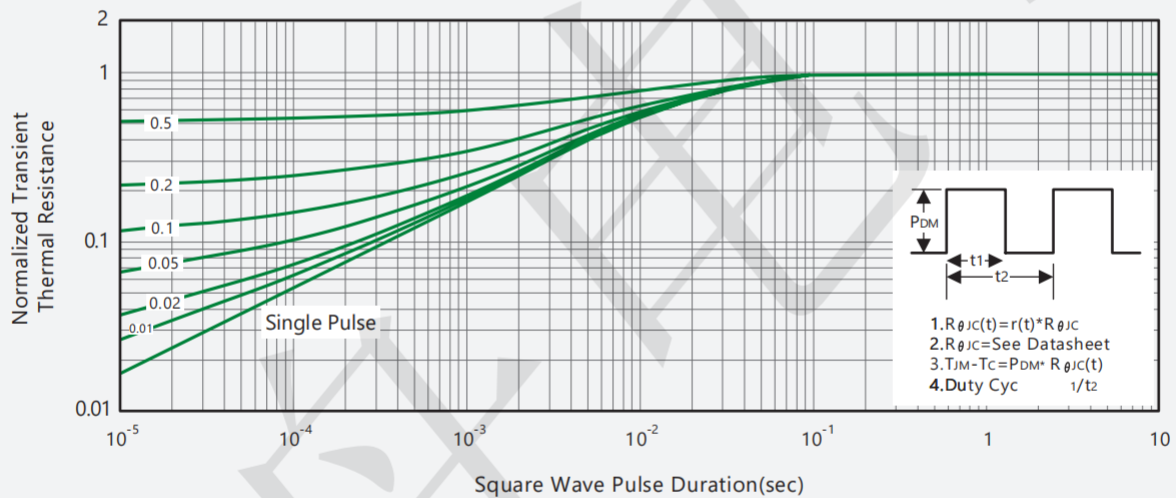
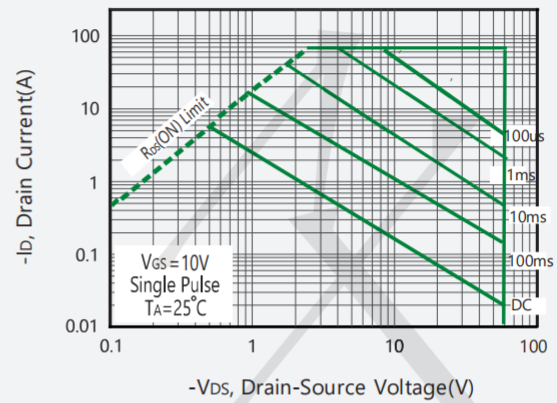
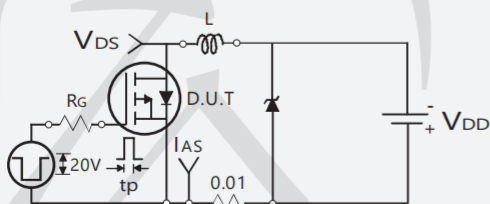
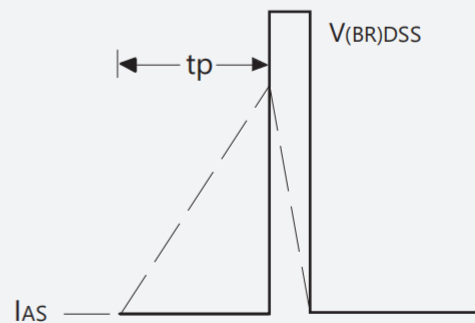


Figure 9. Normalized Thermal Transient Impedance Curve



Unclamped Inductive Test Circuit

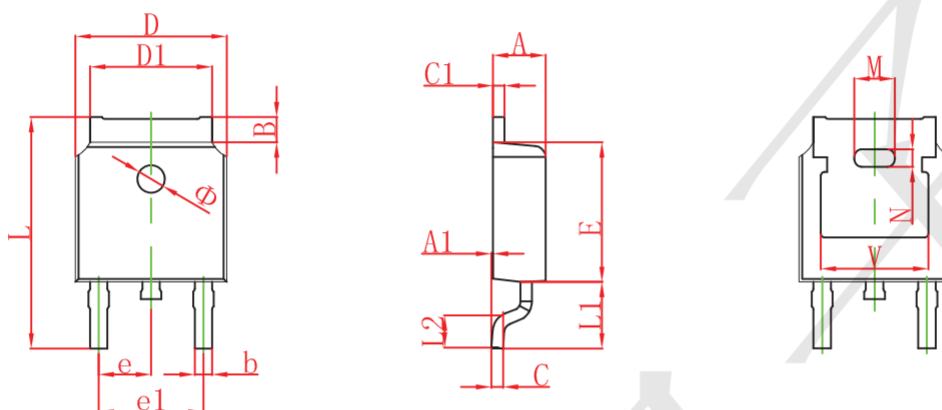
Figure 11a.



Unclamped Inductive Waveforms

Figure 11b.

TO252 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.200	2.380	0.087	0.094
A1	0.000	0.100	0.000	0.004
B	0.800	1.400	0.031	0.055
b	0.710	0.810	0.028	0.032
c	0.460	0.560	0.018	0.022
c1	0.460	0.560	0.018	0.022
D	6.500	6.700	0.256	0.264
D1	5.130	5.460	0.202	0.215
E	6.000	6.200	0.236	0.244
e	2.286 TYP.		0.090 TYP.	
e1	4.327	4.727	0.170	0.186
M	1.778 REF.		0.070 REF.	
N	0.762 REF.		0.018 REF.	
L	9.800	10.400	0.386	0.409
L1	2.9 REF.		0.114 REF.	
L2	1.400	1.700	0.055	0.067
V	4.830 REF.		0.190 REF.	
Φ	1.100	1.300	0.043	0.051

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